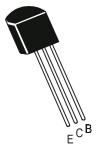




### NPN SILICON EPITAXIAL TRANSISTOR

**CSD545** 

TO-92 Plastic Package



# Low Frequencty Power Amplifier And Convertor Stage Applications.

ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Emitter Voltage	BV <sub>CEO</sub>	25	V
Collector Base Voltage	$BV_CBO$	25	V
Emitter Base Voltage	$BV_{EBO}$	5	V
Collector Current Continuous	I <sub>C</sub>	1	Α
	Peak I <sub>CM</sub>	1.5	Α
Colector Power Dissipation	$P_{D}$	600	mW
<b>Operating And Storage Junction</b>	$T_{i},T_{stq}$	-55 to +150	°C
Temperature Range			

**ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)** 

DESCRIPTION	SYMBOL	. TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Emitter Breakdown Voltage	$BV_CEO$	I <sub>C</sub> =1mA,I <sub>B</sub> =0	25			V
Collector Base Breakdown Voltage	$BV_CBO$	$I_{C}$ =10 $\mu$ A, $I_{B}$ =0	25			V
Emitter Base Breakdown Voltage	$BV_{EBO}$	$I_E$ =10 $\mu$ A, $I_C$ =0	5			V
Collector Cut off Current	$I_{CBO}$	$V_{CB} = 20V, I_{E} = 0$			1.0	μΑ
Emitter Cut off Current	$I_{EBO}$	$V_{BE}$ =4V, $I_{E}$ = 0			1.0	μΑ
DC Current Gain	h <sub>FE (1)</sub>	$V_{CE}$ =2V, $I_{C}$ =50mA	60		560	
	h <sub>FE (2)</sub> *	$V_{CE}$ =2 $V$ , $I_{C}$ =1 $A$	30			
Base Emitter Saturation Voltage	V <sub>BE(sat)</sub> *	I <sub>C</sub> =500mA,I <sub>B</sub> =50mA		0.85	1.2	V
Collector Emitter Saturation Voltage	V <sub>CE(sat)</sub> *	I <sub>C</sub> =500mA,I <sub>B</sub> =50mA		0.1	0.3	V

**ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)** 

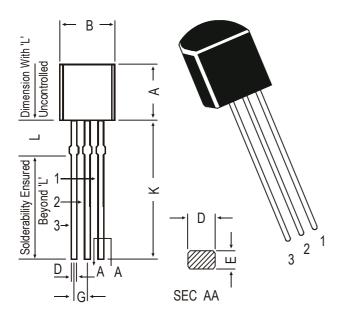
DESCRIPTION	SYMBO	L TEST CONDITION	MIN	TYP	MAX	UNIT
DYNAMIC CHARACTERISTICS						
Transition Frequency	$f_T$	$I_C$ =50mA, $V_{CE}$ =10V		180		MHz
Collector Output Capacitance	$C_ob$	$I_E=0, V_{CB}=10V$		15		pF
		f=1MHz				-

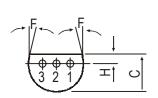
CLASSIFICATION	D	E	F	G	
h <sub>FE</sub> (1)	60-120	100-200	160-320	280-560	
*Pulse Condition: Width < 300μs	, Duty Cycle ≤ 2%.				

# **TO-92 Plastic Package**

## **TO-92 Plastic Package**

#### **TO-92 Transistors on Tape and Ammo Pack**





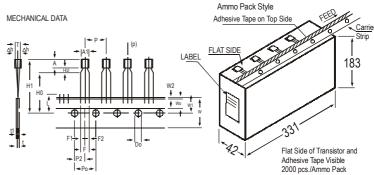
PIN CONFIGURATION

2. COLLECTOR 3. EMITTER

1. BASE

DIM	MIN.	MAX.
Α	4.32	5.33
В	4.45	5.20
С	3.18	4.19
D	0.41	0.55
Е	0.35	0.50
F	5 D	EG
G	1.14	1.40
Ι	1.14	1.53
K	12.70	_
L	1.982	2.082

All diminsions in mm.



#### All dimensions in mm unless specified otherwise

ſ	ITEM		SPECIFICATION				
L	ITEM	SYMBOL	MIN.	MIN. NOM. MAX. TO		TOL.	REMARKS
	BODY WIDTH BODY HEIGHT BODY THICKNESS PITCH OF COMPONENT FEED HOLE PITCH	A1 A T P	4.0 4.8 3.9	12.7 12.7	4.8 5.2 4.2	±1 ±0.3	CUMULATIVE PITCH
	FEED HOLE CENTRE TO COMPONENT CENTRE	P0 P2		6.35		±0.3	ERROR 1.0 mm/20 PITCH TO BE MEASURED AT BOTTOM OF CLINCH
	DISTANCE BETWEEN OUTER LEADS COMPONENT ALIGNMENT TAPE WIDTH HOLD-DOWN TAPE WIDTH HOLE POSITION	F △h W Wo W1		5.08 0 18 6	1	+0.6 -0.2 ±0.5 ±0.2 +0.7 -0.5	AT TOP OF BODY
	HOLD-DOWN TAPE POSITION LEAD WIRE CLINCH HEIGHT COMPONENT HEIGHT LENGTH OF SNIPPED LEADS FEED HOLE DIAMETER TOTAL TAPE THICKNESS LEAD - TO - LEAD DISTANCEF1,	W2 Ho H1 L Do t F2		0.5 16 4 2.54	23.25 11.0 1.2	±0.2 ±0.5 ±0.2 +0.4 -0.1	t1 0.3 - 0.6
	CLINCH HEIGHT PULL - OUT FORCE	H2 (P)	6N		3	-0.1	

- NOTES

  1. MAXIMUM ALIGNMENT DEVIATION BETWEEN LEADS NOT TO BE GREATER THAN 0.2 mm.
  2. MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCE
- MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCEED 1 mm IN 20 PITCHES.
- HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO
- EXPOSURE OF ADHESIVE.
  4. NO MORE THAN 3 CONSECUTIVE MISSING COMPONENTS ARE PERMITTED.
- A TAPE TRAILER, HAVING AT LEAST THREE FEED HOLES ARE REQUIRED AFTER THE LAST COMPONENT.
- 6. SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

# **Packing Detail**

1 doking bottom								
PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX			
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt	
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs	
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs	

Notes CSD545

TO-92 Plastic Package

#### **Disclaimer**

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